Octal D-type transparent latch; 3-state Rev. 5 — 13 December 2011

Product data sheet

#### **General description** 1.

The 74HC373; 74HCT373 is a high-speed Si-gate CMOS device and is pin compatible with Low-power Schottky TTL. It is specified in compliance with JEDEC standard no. 7A.

The 74HC373; 74HCT373 is an octal D-type transparent latch featuring separate D-type inputs for each latch and 3-state outputs for bus oriented applications. A latch enable (LE) input and an output enable  $(\overline{OE})$  input are common to all latches.

The 74HC373; 74HCT373 consists of eight D-type transparent latches with 3-state true outputs. When LE is HIGH, data at the Dn inputs enters the latches. In this condition the latches are transparent, i.e. a latch output will change state each time its corresponding D input changes.

When LE is LOW the latches store the information that was present at the D inputs a set-up time preceding the HIGH-to-LOW transition of LE. When OE is LOW, the contents of the 8 latches are available at the outputs. When OE is HIGH, the outputs go to the highimpedance OFF-state. Operation of the OE input does not affect the state of the latches.

The 74HC373; 74HCT373 is functionally identical to:

- 74HC563; 74HCT563: but inverted outputs and different pin arrangement
- 74HC573; 74HCT573: but different pin arrangement

#### **Features and benefits** 2.

- 3-state non-inverting outputs for bus oriented applications
- Common 3-state output enable input
- Functionally identical to the 74HC563; 74HCT563 and 74HC573; 74HCT573
- ESD protection:
  - HBM JESD22-A114F exceeds 2 000 V
  - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

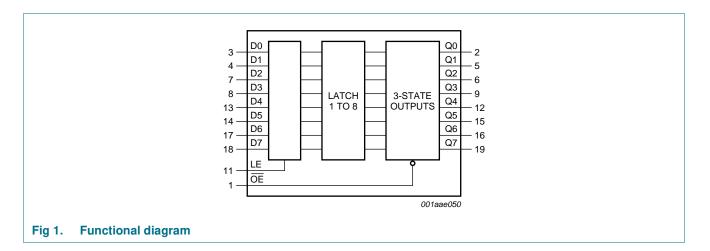


Octal D-type transparent latch; 3-state

## 3. Ordering information

Table 1. Orc	lering information				
Type number	Package				
	Temperature range	Name	Description	Version	
74HC373N	-40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1	
74HCT373N					
74HC373D	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads;	SOT163-1	
74HCT373D			body width 7.5 mm		
74HC373DB	–40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads;	SOT339-1	
74HCT373DB			body width 5.3 mm		
74HC373PW	–40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads;	SOT360-1	
74HCT373PW			body width 4.4 mm		
74HC373BQ	–40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced very	SOT764-1	
74HCT373BQ			thin quad flat package; no leads; 20 terminals; body $2.5 \times 4.5 \times 0.85$ mm		

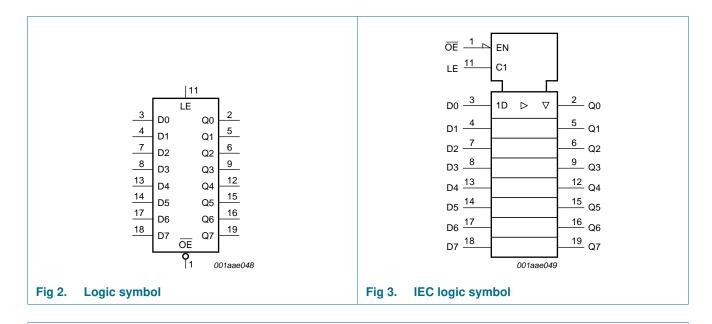
## 4. Functional diagram

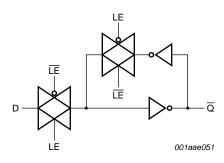


### **NXP Semiconductors**

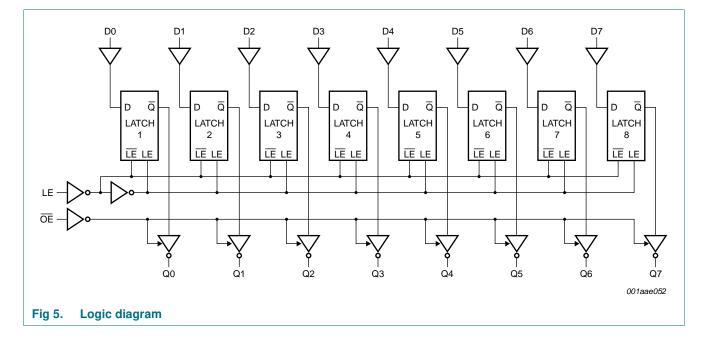
# 74HC373; 74HCT373

Octal D-type transparent latch; 3-state





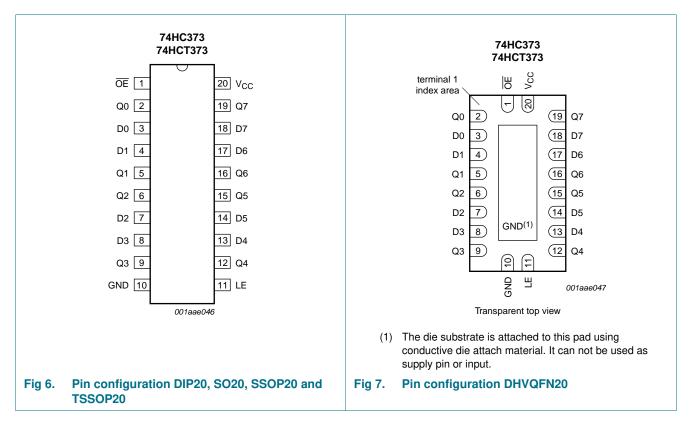
#### Fig 4. Logic diagram (one latch)



Octal D-type transparent latch; 3-state

### 5. Pinning information

### 5.1 Pinning



### 5.2 Pin description

Table 2. Pin description		
Symbol	Pin	Description
OE	1	3-state output enable input (active LOW)
Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7	2, 5, 6, 9, 12, 15, 16, 19	3-state latch output
D0, D1, D2, D3, D4, D5, D6, D7	3, 4, 7, 8, 13, 14, 17, 18	data input
GND	10	ground (0 V)
LE	11	latch enable input (active HIGH)
V <sub>CC</sub>	20	supply voltage

Octal D-type transparent latch; 3-state

### 6. Functional description

### 6.1 Function table

#### Table 3.Function table<sup>[1]</sup>

Operating mode	Control		Input	Internal latches	Output
	OE	LE	Dn		Qn
Enable and read register	L	Н	L	L	L
(transparent mode)			Н	Н	Н
Latch and read register	L	L	I	L	L
			h	Н	Н
Latch register and disable outputs	Н	Х	Х	Х	Z

[1] H = HIGH voltage level;

h = HIGH voltage level one set-up time prior to the HIGH-to-LOW LE transition;

L = LOW voltage level;

I = LOW voltage level one set-up time prior to the HIGH-to-LOW LE transition;

X = don't care;

Z = high-impedance OFF-state.

### 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{CC}$ + 0.5 V	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5$ V or $V_O > V_{CC}$ + 0.5 V	-	±20	mA
lo	output current	$V_{O}=-0.5$ V to $(V_{CC}$ + 0.5 V)	-	±35	mA
I <sub>CC</sub>	supply current		-	+70	mA
I <sub>GND</sub>	ground current		-	-70	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation				
		DIP20 package	<u>[1]</u> -	750	mW
		SO20 package	[2] _	500	mW
		SSOP20 package	[3]	500	mW
		TSSOP20 package	[3]	500	mW
		DHVQFN20 package	<u>[4]</u> _	500	mW

[1] For DIP20 package:  $P_{tot}$  derates linearly with 12 mW/K above 70  $^\circ\text{C}.$ 

[2] For SO20:  $P_{tot}$  derates linearly with 8 mW/K above 70  $^\circ\text{C}.$ 

[3] For SSOP20 and TSSOP20 packages: P<sub>tot</sub> derates linearly with 5.5 mW/K above 60  $^\circ$ C.

[4] For DHVQFN20 package: Ptot derates linearly with 4.5 mW/K above 60 °C.

Octal D-type transparent latch; 3-state

#### **Recommended operating conditions** 8.

#### **Recommended operating conditions** Table 5.

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	-	74HC373	3	7	4HCT37	3	Unit
			Min	Тур	Max	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	$V_{CC}$	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	$V_{CC}$	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

#### **Static characteristics** 9.

#### Static characteristics 74HC373 Table 6.

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 25	°C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	V
		$V_{CC} = 4.5 V$	3.15	2.4	-	V
		$V_{CC} = 6.0 V$	4.2	3.2	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	V
		$V_{CC} = 4.5 V$	-	2.1	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$	-	-	-	
		$I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	2.0	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	4.5	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	0	0.1	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V
		$I_{O} = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	V
lı	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±0.1	μA
I <sub>OZ</sub>	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 6.0 \text{ V};$ $V_{O} = V_{CC} \text{ or GND}$	-	-	±0.5	μA
I <sub>CC</sub>	supply current	$V_{CC} = 6.0 \text{ V}; I_O = 0 \text{ A};$ $V_1 = V_{CC} \text{ or GND}$	-	-	8.0	μA
Cı	input capacitance		-	3.5	-	pF
4HC_HCT373		All information provided in this document is subject to legal disclaimers.		C	NXP B.V. 2011.	All rights reser
Product da	ta sheet	Rev. 5 — 13 December 2011				6 of

Octal D-type transparent latch; 3-state

Symbol	Parameter	Conditions	Min	Тур	Max	Uni
T <sub>amb</sub> = -4	0 °C to +85 °C					
VIH	HIGH-level input voltage	$V_{CC} = 2.0 V$	1.5	-	-	V
		$V_{CC} = 4.5 V$	3.15	-	-	V
		$V_{CC} = 6.0 V$	4.2	-	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC} = 2.0 V$	-	-	0.5	V
		$V_{CC} = 4.5 V$	-	-	1.35	V
		$V_{\rm CC} = 6.0 \ V$	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = -20 \ \mu A; V_{CC} = 2.0 \ V$	1.9	-	-	V
		$I_{O} = -20 \ \mu A; V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_{O} = -20 \ \mu A; V_{CC} = 6.0 \ V$	5.9	-	-	V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.34	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH}$ or $V_{IL}$				
		$I_{O} = 20 \ \mu A; V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	-	0.1	V V 3 V 3 V 3 V 0 μA
		$I_{O} = 20 \ \mu A; V_{CC} = 6.0 \ V$	-	-	0.1	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.33	V
		I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V	-	-	0.33	V
I <sub>I</sub>	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±1.0	μA
l <sub>oz</sub>	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 6.0 \text{ V};$ $V_{O} = V_{CC} \text{ or GND}$	-	-	±5.0	μA
lcc	supply current	$V_{CC}$ = 6.0 V; I <sub>O</sub> = 0 A; V <sub>I</sub> = V <sub>CC</sub> or GND		-	80	μA
T <sub>amb</sub> = -4	0 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 2.0 V$	1.5	-	-	V
		$V_{CC} = 4.5 V$	3.15	-	-	V
		$V_{CC} = 6.0 V$	4.2	-	-	V
VIL	LOW-level input voltage	$V_{CC} = 2.0 V$	-	-	0.5	V
		$V_{CC} = 4.5 V$	-	-	1.35	V
		$V_{\rm CC} = 6.0 \ V$	-	-	1.8	V
V <sub>он</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = -20 \ \mu A; V_{CC} = 2.0 \ V$	1.9	-	-	V
		$I_{O} = -20 \ \mu A; V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_{\rm O} = -20 \ \mu \text{A}; \ V_{\rm CC} = 6.0 \ \text{V}$	5.9	-	-	V
		$I_0 = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		$I_{\rm O} = -7.8$ mA; $V_{\rm CC} = 6.0$ V	5.2	-	-	V

### Table 6. Static characteristics 74HC373 ... continued

Octal D-type transparent latch; 3-state

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.4	V
		$I_{O} = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.4	V
I	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±1.0	μA
I <sub>OZ</sub>	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 6.0 \text{ V};$ $V_{O} = V_{CC} \text{ or GND}$	-	-	±10.0	μA
I <sub>CC</sub>	supply current	$V_{CC}$ = 6.0 V; I <sub>O</sub> = 0 A; V <sub>I</sub> = V <sub>CC</sub> or GND	-	-	160	μA

### Table 6. Static characteristics 74HC373 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

#### Table 7. Static characteristics 74HCT373

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 25	°C					
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$	2.0	1.6	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC} = 4.5 V$ to 5.5 V	-	1.2	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	4.5	-	V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0.0	0.1	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.16	0.26	V
lı	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5$ V	-	-	±0.1	μA
I <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 5.5$ V; $V_O = V_{CC}$ or GND per input pin; other inputs at $V_{CC}$ or GND; $I_O = 0$ A	-	-	±0.5	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	8.0	μA
$\Delta I_{CC}$	additional supply current	$      V_I = V_{CC} - 2.1 \text{ V}; \\       other inputs at V_{CC} \text{ or GND}; \\       V_{CC} = 4.5 \text{ V to 5.5 V}; I_O = 0 \text{ A} $				
		Dn	-	30	108	μA
		LE	-	150	540	μA
		ŌĒ	-	100	360	μA
CI	input capacitance		-	3.5	-	pF
$T_{amb} = -4$	0 °C to +85 °C					
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V}$ to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$	-	-	0.8	V

Octal D-type transparent latch; 3-state

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>ОН</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_O = -6.0 \ \mu A; \ V_{CC} = 4.5 \ V$	3.84	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.33	V
l <sub>l</sub>	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±1.0	μA
I <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 5.5$ V; $V_O = V_{CC}$ or GND per input pin; other inputs at $V_{CC}$ or GND; $I_O = 0$ A	-	-	±5.0	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	80	μA
∆l <sub>CC</sub>	additional supply current	$      V_I = V_{CC} - 2.1 \text{ V}; \\       other inputs at V_{CC} \text{ or GND}; \\       V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; I_O = 0 \text{ A} $				
		Dn	-	-	135	μA
		LE	-	-	675	μA
		ŌĒ	-	-	450	μA
T <sub>amb</sub> = -4	0 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V}$ to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_O = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.4	V
lı	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5$ V	-	-	±1.0	μA
I <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 5.5 V$ ; $V_O = V_{CC}$ or GND per input pin; other inputs at $V_{CC}$ or GND; $I_O = 0 A$	-	-	±10	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC} \text{ or GND}; I_O = 0 \text{ A};$ $V_{CC} = 5.5 \text{ V}$	-	-	160	μA
∆l <sub>CC</sub>	additional supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} - 2.1 \ V; \\ \text{other inputs at } V_{CC} \ \text{or GND}; \\ V_{CC} = 4.5 \ V \ \text{to } 5.5 \ V; \ I_{O} = 0 \ A \end{array}$				
		Dn	-	-	147	μA
		LE	-	-	735	μA
		OE	-	-	490	μA

#### Static characteristics 74HCT373 ... continued Table 7.

Octal D-type transparent latch; 3-state

### **10. Dynamic characteristics**

### Table 8. Dynamic characteristics 74HC373

Voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$  unless otherwise specified; for test circuit see <u>Figure 12</u>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
r <sub>amb</sub> = 2	5 °C					
bd	propagation delay	Dn to Qn; see Figure 8	<u>[1]</u>			
		$V_{CC} = 2.0 V$	-	41	150	ns
		$V_{CC} = 4.5 V$	-	15	30	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	12	-	ns
		$V_{CC} = 6.0 V$	-	12	26	ns
		LE to Qn; see Figure 9				
		$V_{CC} = 2.0 V$	-	50	175	ns
		$V_{CC} = 4.5 V$	-	18	35	ns
		$V_{CC} = 5 V; C_L = 15 pF$	-	15	-	ns
		$V_{CC} = 6.0 V$	-	14	30	ns
en	enable time	OE to Qn; see Figure 10	[2]			
		$V_{CC} = 2.0 V$	-	44	150	ns
		$V_{CC} = 4.5 V$	-	16	30	ns
		$V_{CC} = 6.0 V$	-	13	26	ns
t <sub>dis</sub>	disable time	OE to Qn; see Figure 10	[3]			
		$V_{CC} = 2.0 V$	-	47	150	ns
		$V_{CC} = 4.5 V$	-	17	30	ns
		$V_{CC} = 6.0 V$	-	14	26	ns
t	transition time	Qn; see Figure 8 and Figure 9	[4]			
		$V_{CC} = 2.0 V$	-	14	60	ns
		$V_{CC} = 4.5 V$	-	5	12	ns
		$V_{CC} = 6.0 V$	-	4	10	ns
W	pulse width	LE HIGH; see Figure 9				
		$V_{CC} = 2.0 V$	80	17	-	ns
		$V_{CC} = 4.5 V$	16	6	-	ns ns ns ns ns
		$V_{CC} = 6.0 V$	14	5	-	ns
su	set-up time	Dn to LE; see Figure 11				
		$V_{CC} = 2.0 V$	50	14	-	ns
		$V_{CC} = 4.5 V$	10	5	-	ns
		$V_{CC} = 6.0 V$	9	4	-	ns
h	hold time	Dn to LE; see Figure 11				
		$V_{CC} = 2.0 V$	+5	-8	-	ns
		$V_{CC} = 4.5 V$	+5	-3	-	ns
		$V_{\rm CC} = 6.0 \ V$	+5	-2	-	ns
C <sub>PD</sub>	power dissipation capacitance	per latch; $V_I = GND$ to $V_{CC}$	<u>[5]</u> _	45	-	pF

Octal D-type transparent latch; 3-state

Symbo	Parameter	Conditions	Min	Тур	Max	Unit
Г <sub>атb</sub> =	–40 °C to +85 °C					
pd	propagation delay	Dn to Qn; see Figure 8	[1]			
		$V_{CC} = 2.0 V$	-	-	190	ns
		$V_{CC} = 4.5 V$	-	-	38	ns
		$V_{CC} = 6.0 V$	-	-	33	ns
		LE to Qn; see Figure 9				
		$V_{CC} = 2.0 V$	-	-	220	ns
		$V_{CC} = 4.5 V$	-	-	44	ns
		$V_{CC} = 6.0 V$	-	-	37	ns
en	enable time	OE to Qn; see Figure 10	[2]			
		$V_{CC} = 2.0 V$	-	-	190	ns
		$V_{CC} = 4.5 V$	-	-	38	ns
		$V_{CC} = 6.0 V$	-	-	33	ns
dis	disable time	OE to Qn; see Figure 10	[3]			
		$V_{CC} = 2.0 V$	-	-	190	ns
		$V_{CC} = 4.5 V$	-	-	38	ns
		$V_{CC} = 6.0 V$	-	-	33	ns
	transition time	Qn; see Figure 8 and Figure 9	<u>[4]</u>			
		$V_{CC} = 2.0 V$	-	-	75	ns
		$V_{CC} = 4.5 V$	-	-	15	ns
		$V_{CC} = 6.0 V$	-	-	13	ns
v	pulse width	LE HIGH; see Figure 9				
		$V_{CC} = 2.0 V$	100	-	-	ns ns ns ns ns ns ns ns ns ns ns ns ns n
		$V_{CC} = 4.5 V$	20	-	-	ns
		$V_{CC} = 6.0 V$	17	-	-	ns
u	set-up time	Dn to LE; see Figure 11				
		$V_{CC} = 2.0 V$	65	-	-	ns
		$V_{CC} = 4.5 V$	13	-	-	ns
		$V_{CC} = 6.0 V$	11	-	-	ns
ı	hold time	Dn to LE; see Figure 11				
		$V_{CC} = 2.0 V$	5	-	-	ns
		$V_{CC} = 4.5 V$	5	-	-	ns

#### Dynamic characteristics 74HC373 ... continued Table 8.

 $V_{CC} = 6.0 V$ 

5

-

-

ns

Octal D-type transparent latch; 3-state

### Table 8. Dynamic characteristics 74HC373 ...continued

Voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$  unless otherwise specified; for test circuit see Figure 12.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	-40 °C to +125 °C					
t <sub>pd</sub>	propagation delay	Dn to Qn; see Figure 8	[1]			
		$V_{CC} = 2.0 V$	-	-	225	ns
		$V_{CC} = 4.5 V$	-	-	45	ns
		$V_{CC} = 6.0 V$	-	-	38	ns
		LE to Qn; see Figure 9				
		$V_{CC} = 2.0 V$	-	-	265	ns
		$V_{CC} = 4.5 V$	-	-	53	ns
		$V_{CC} = 6.0 V$	-	-	45	ns
t <sub>en</sub>	enable time	OE to Qn; see Figure 10	[2]			
		$V_{CC} = 2.0 V$	-	-	225	ns
		$V_{CC} = 4.5 V$	-	-	45	ns
		$V_{CC} = 6.0 V$	-	-	38	ns
t <sub>dis</sub>	<sub>dis</sub> disable time	OE to Qn; see Figure 10	[3]			
		$V_{CC} = 2.0 V$	-	-	225	ns
		$V_{CC} = 4.5 V$	-	-	45	ns
		$V_{CC} = 6.0 V$	-	-	38	ns
t	transition time	Qn; see Figure 8 and Figure 9	[4]			
		$V_{CC} = 2.0 V$	-	-	90	ns
		$V_{CC} = 4.5 V$	-	-	18	ns
		$V_{CC} = 6.0 V$	-	-	15	ns
w	pulse width	LE HIGH; see Figure 9				
		$V_{CC} = 2.0 V$	120	-	-	ns
		$V_{CC} = 4.5 V$	24	-	-	ns
		$V_{CC} = 6.0 V$	20	-	-	ns
su	set-up time	Dn to LE; see Figure 11				
		$V_{CC} = 2.0 V$	75	-	-	ns
		V <sub>CC</sub> = 4.5 V	15	-	-	ns
		$V_{CC} = 6.0 V$	13	-	-	ns

### Octal D-type transparent latch; 3-state

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t <sub>h</sub>	hold time	Dn to LE; see Figure 11				
	$V_{CC} = 2.0 V$	5	-	-	ns	
		$V_{CC} = 4.5 V$	5	-	-	ns
		$V_{CC} = 6.0 V$	5	-	-	ns

#### Table 8. Dynamic characteristics 74HC373 ... continued

Voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$  unless otherwise specified; for test circuit see Figure 12.

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[2]  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .

[3]  $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .

[4]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .

[5]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W).

$$\begin{split} P_D &= C_{PD} \times V_{CC}{}^2 \times f_i \times N + \sum (C_L \times V_{CC}{}^2 \times f_o) \text{ where:} \\ f_i &= \text{input frequency in MHz;} \\ f_o &= \text{output frequency in MHz;} \\ C_L &= \text{output load capacitance in pF;} \\ V_{CC} &= \text{supply voltage in V;} \\ N &= \text{number of inputs switching;} \end{split}$$

 $\Sigma(C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$ 

#### Table 9. Dynamic characteristics 74HCT373

Voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$  unless otherwise specified; for test circuit see <u>Figure 12</u>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	5 °C					
t <sub>pd</sub>	propagation delay	Dn to Qn; see Figure 8	<u>[1]</u>			
		$V_{CC} = 4.5 V$	-	17	30	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	14	-	ns
		LE to Qn; see Figure 9				
		$V_{CC} = 4.5 V$	-	16	32	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	13	-	ns
t <sub>en</sub>	enable time	OE to Qn; see Figure 10	[2]			
		$V_{CC} = 4.5 V$	-	19	32	ns
dis	<sub>is</sub> disable time	OE to Qn; see Figure 10	[3]			
	$V_{CC} = 4.5 V$	-	18	30	ns	
t	transition time	Qn; see Figure 8 and Figure 9	[4]			
		$V_{CC} = 4.5 V$	-	5	12	ns
W	pulse width	LE HIGH; see Figure 9				
		$V_{CC} = 4.5 V$	16	4	-	ns
su	set-up time	Dn to LE; see Figure 11				
		$V_{CC} = 4.5 V$	12	6	-	ns
h	hold time	Dn to LE; see Figure 11				
		$V_{CC} = 4.5 V$	4	-1	-	ns
C <sub>PD</sub>	power dissipation capacitance	per latch; V <sub>I</sub> = GND to (V <sub>CC</sub> – 1.5 V)	<u>[5]</u> _	41	-	pF

Octal D-type transparent latch; 3-state

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Г <sub>атb</sub> = -	40 °C to +85 °C					
pd	propagation delay	Dn to Qn; see Figure 8	[1]			
		$V_{CC} = 4.5 V$	-	-	38	ns
		LE to Qn; see Figure 9				
		$V_{CC} = 4.5 V$	-	-	40	ns
en	enable time	OE to Qn; see Figure 10	[2]			
		$V_{CC} = 4.5 V$	-	-	40	ns
is	disable time	OE to Qn; see Figure 10	[3]			
		$V_{CC} = 4.5 V$	-	-	38	ns
	transition time	Qn; see Figure 8 and Figure 9	[4]			
		$V_{CC} = 4.5 V$	-	-	15	ns
v	pulse width	LE HIGH; see Figure 9				
		$V_{CC} = 4.5 V$	20	-	-	ns
u	set-up time	Dn to LE; see Figure 11				
		$V_{CC} = 4.5 V$	15	-	-	ns
	hold time	Dn to LE; see Figure 11				
		$V_{CC} = 4.5 V$	4	-	-	ns
amb = -	40 °C to +125 °C					
d	propagation delay	Dn to Qn; see Figure 8	[1]			
		$V_{CC} = 4.5 V$	-	-	45	ns
		LE to Qn; see Figure 9				
		$V_{CC} = 4.5 V$	-	-	48	ns
n	enable time	OE to Qn; see Figure 10	[2]			
		$V_{CC} = 4.5 V$	-	-	48	ns
lis	disable time	OE to Qn; see Figure 10	[3]			
		$V_{CC} = 4.5 V$	-	-	45	ns
transition time	Qn; see Figure 8 and Figure 9	[4]				
		$V_{CC} = 4.5 V$	-	-	18	ns
V	pulse width	LE HIGH; see Figure 9				
		$V_{CC} = 4.5 V$	24	-	-	ns
u	set-up time Dn to LE	Dn to LE; see Figure 11				
	$V_{CC} = 4.5 V$	18	-	-	ns	

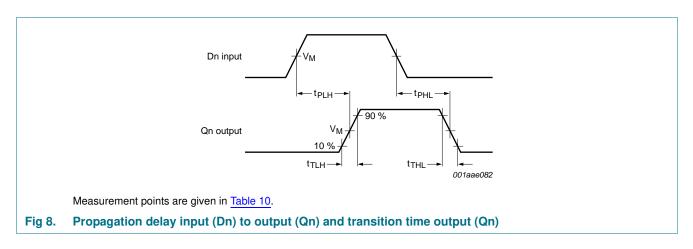
#### Table 9 Dynamic characteristics 74HCT373 ... continued

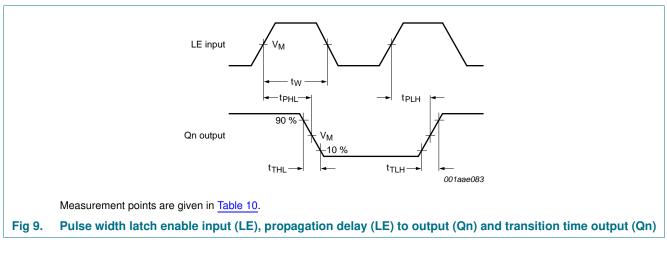
### Octal D-type transparent latch; 3-state

Symb	ool Parameter	Conditions	Min	Тур	Max	Unit
t <sub>h</sub>	hold time Dn to LE	Dn to LE; see Figure 11				
		$V_{CC} = 4.5 V$	4	-	-	ns
[1] t <sub>p</sub>	$_{\rm d}$ is the same as $t_{\rm PLH}$ and $t_{\rm PHL}.$					
[2] t <sub>e</sub>	$_{\rm n}$ is the same as $t_{\rm PZH}$ and $t_{\rm PZL}.$					
[3] t <sub>d</sub>	3] t <sub>dis</sub> is the same as t <sub>PLZ</sub> and t <sub>PHZ</sub> .					
[4] t <sub>t</sub>	$t_{t}$ is the same as $t_{THL}$ and $t_{TLH}$ .					
[5] C	PD is used to determine the dynamic p	power dissipation ( $P_D$ in $\mu W$ ).				
Р	$D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2)^2$	$x \times f_{o}$ ) where:				
fi	<ul><li>input frequency in MHz;</li></ul>					
fo	= output frequency in MHz;					
С	$E_{L}$ = output load capacitance in pF;					
V	<sub>CC</sub> = supply voltage in V;					
Ν	= number of inputs switching;					
Σ	$(C_1 \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$					

### Table 9. Dynamic characteristics 74HCT373 ... continued

### 11. Waveforms





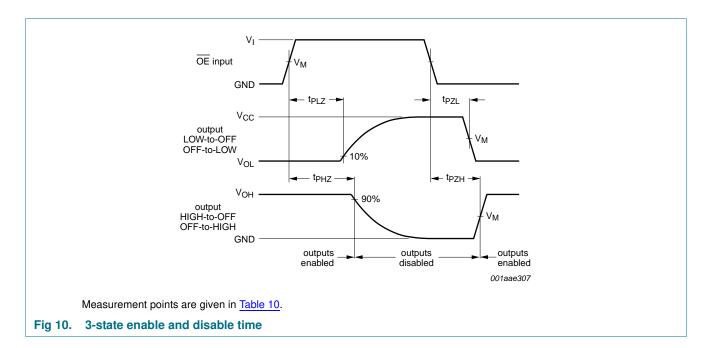
All information provided in this document is subject to legal disclaimers.

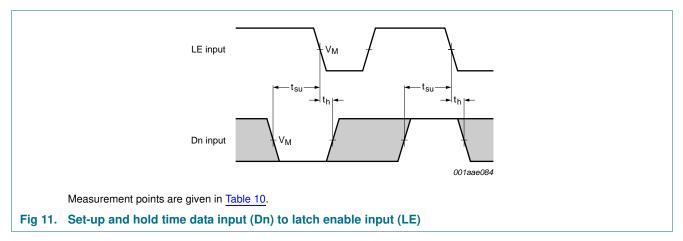
74HC\_HCT373

### **NXP Semiconductors**

# 74HC373; 74HCT373

Octal D-type transparent latch; 3-state





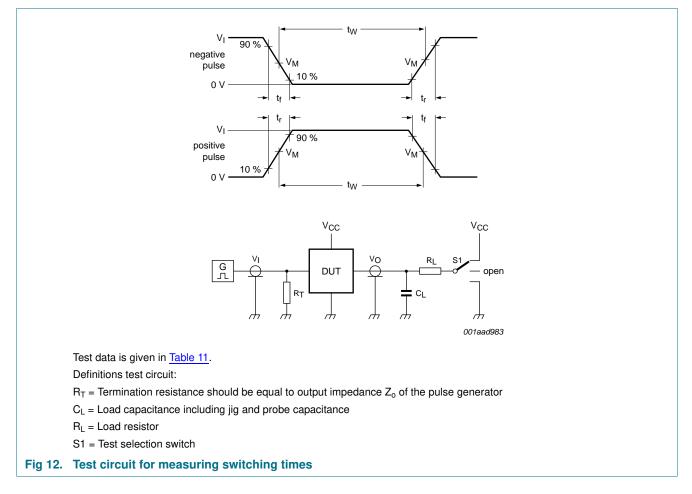
### Table 10.Measurement points

Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74HC373	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
74HCT373	1.3 V	1.3 V

### **NXP Semiconductors**

# 74HC373; 74HCT373

### Octal D-type transparent latch; 3-state

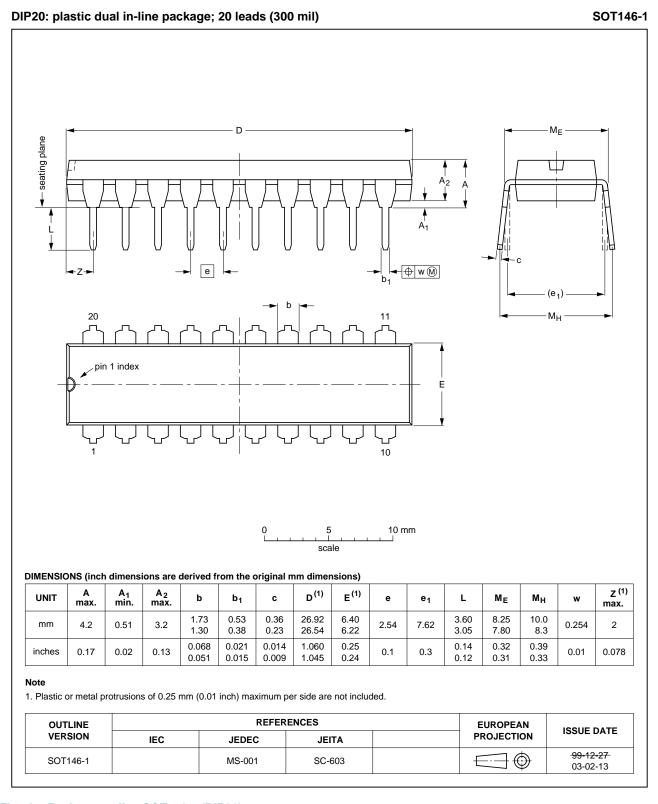


#### Table 11. Test data

Туре	Input		Load		S1 position		
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PHL</sub> , t <sub>PLH</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
74HC373	V <sub>CC</sub>	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>
74HCT373	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>

Octal D-type transparent latch; 3-state

### 12. Package outline



### Fig 13. Package outline SOT146-1 (DIP20)

All information provided in this document is subject to legal disclaimers.

74HC HCT373

18 of 26

Octal D-type transparent latch; 3-state

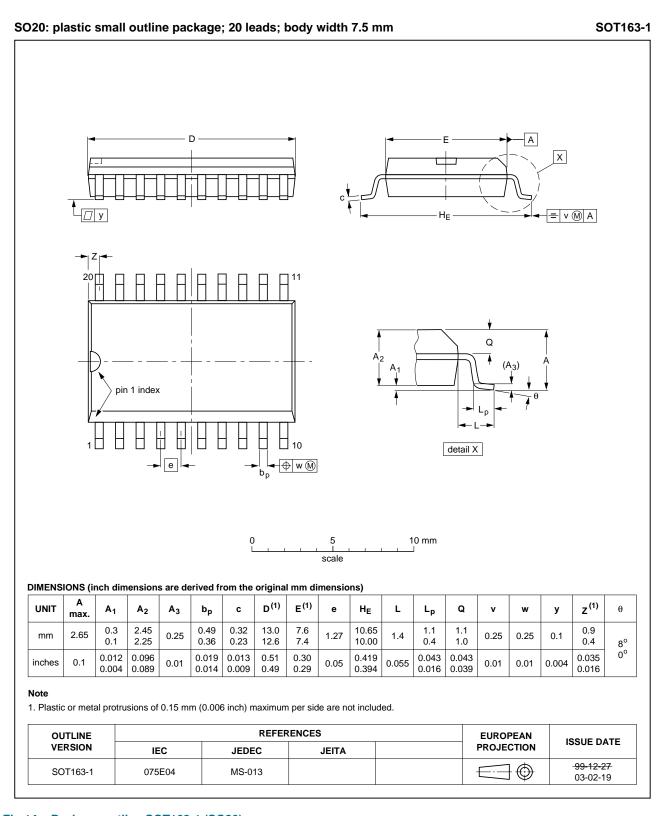


Fig 14. Package outline SOT163-1 (SO20)

74HC HCT373

Octal D-type transparent latch; 3-state

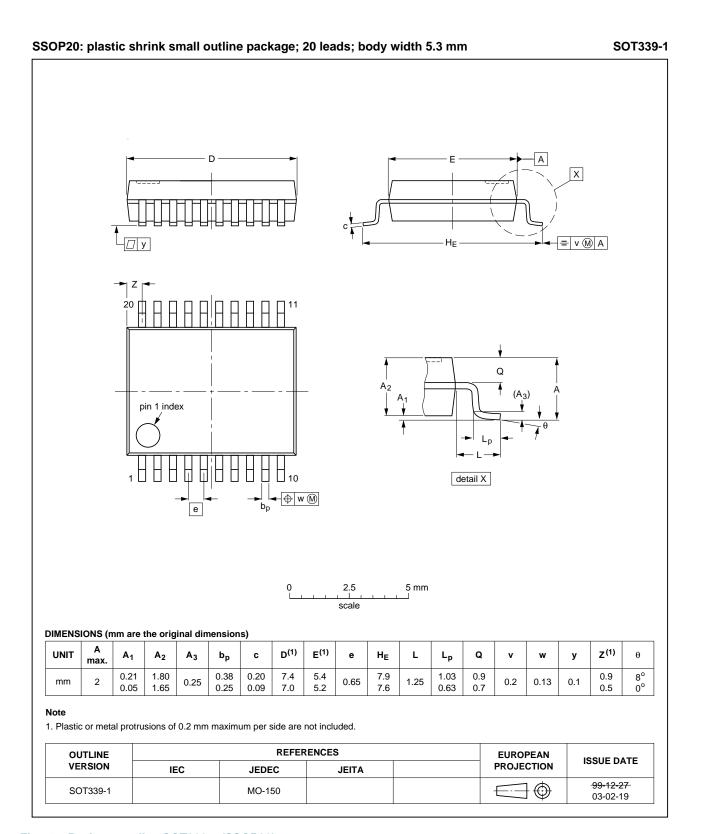
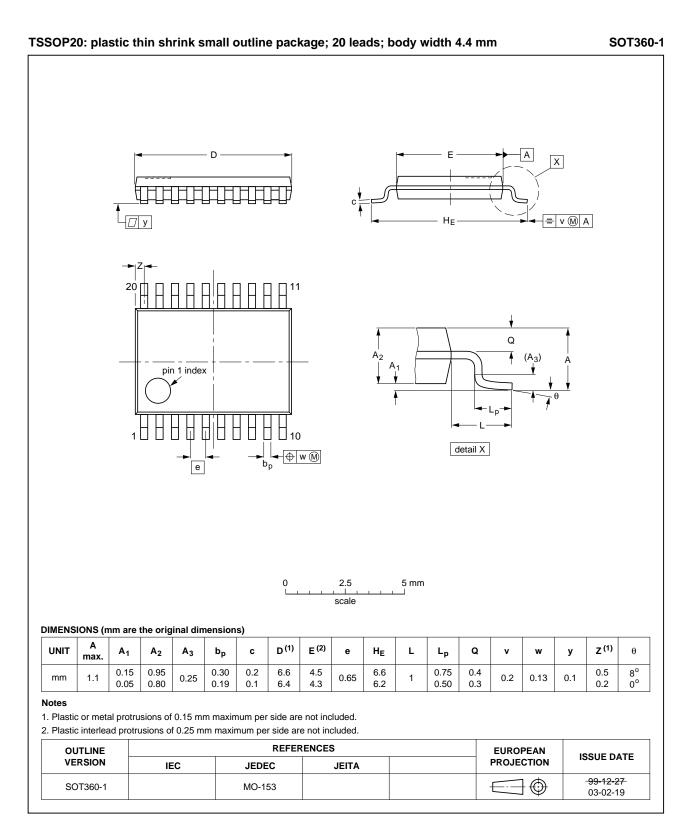


Fig 15. Package outline SOT339-1 (SSOP20)

74HC\_HCT373

Octal D-type transparent latch; 3-state

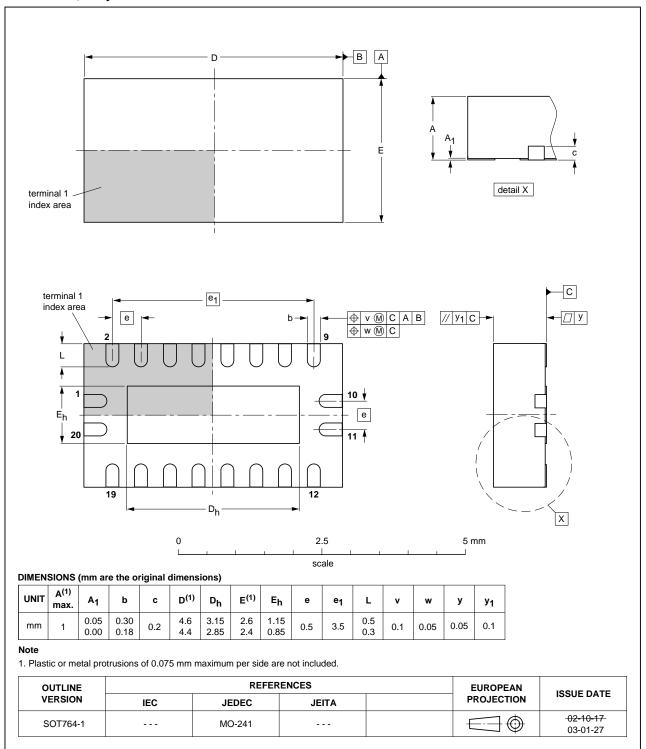


#### Fig 16. Package outline SOT360-1 (TSSOP20)

All information provided in this document is subject to legal disclaimers.

74HC\_HCT373

Octal D-type transparent latch; 3-state



DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm SOT764-1

### Fig 17. Package outline SOT764-1 (DHVQFN20)

All information provided in this document is subject to legal disclaimers.

74HC HCT373

Octal D-type transparent latch; 3-state

## **13. Abbreviations**

ESD ElectroStatic HBM Human Body MM Machine Moo	
ESD ElectroStatic HBM Human Body MM Machine Moo	
HBM Human Body MM Machine Moo	ry Metal Oxide Semiconductor
MM Machine Moc	Discharge
	Model
TTI Transistor Tr	el
	insistor Logic

## 14. Revision history

### Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT373 v.5	20111213	Product data sheet	-	74HC_HCT373 v.4
Modifications:	<ul> <li>Legal page</li> </ul>	es updated.		
74HC_HCT373 v.4	20100903	Product data sheet	-	74HC_HCT373 v.3
74HC_HCT373 v.3	20060120	Product data sheet	-	74HC_HCT373_CNV v.2
74HC_HCT373_CNV v.2	19970827	Product specification	-	-

Octal D-type transparent latch; 3-state

### **15. Legal information**

### 15.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

### 15.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

### 15.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

**Right to make changes** — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nxp.com/profile/terms">http://www.nxp.com/profile/terms</a>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

74HC\_HCT373

All information provided in this document is subject to legal disclaimers.

© NXP B.V. 2011. All rights reserved.

#### Octal D-type transparent latch; 3-state

**Non-automotive qualified products** — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond

### 16. Contact information

NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

### 15.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: <a href="mailto:salesaddresses@nxp.com">salesaddresses@nxp.com</a>

### Octal D-type transparent latch; 3-state

### 17. Contents

1	General description 1
2	Features and benefits 1
3	Ordering information 2
4	Functional diagram 2
5	Pinning information 4
5.1	Pinning 4
5.2	Pin description 4
6	Functional description 5
6.1	Function table
7	Limiting values 5
8	Recommended operating conditions 6
9	Static characteristics 6
10	Dynamic characteristics 10
11	Waveforms 15
12	Package outline 18
13	Abbreviations 23
14	Revision history 23
15	Legal information 24
15.1	Data sheet status 24
15.2	Definitions 24
15.3	Disclaimers
15.4	Trademarks 25
16	Contact information 25
17	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2011.

All rights reserved.

For more information, please visit: http://www.nxp.com For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 13 December 2011 Document identifier: 74HC\_HCT373